

Due: 6 December 2020 @22 o'clock – **No late homework will be accepted.**

- Consider the BiCMOS follower circuit shown in Figure 1a. The BJT transistor parameters are  $V_{BE,on} = 0.7V$ ,  $V_{CE,sat} = 0.2V$ ,  $V_A = \infty$ , and the depletion mode n-MOSFET parameters are  $V_{TH} = -1.8V$ ,  $k_n = 12mA/V^2$ ,  $\lambda = 0$  (You can treat depletion mode MOSFETs as regular MOSFETs).
  - Determine the maximum and minimum values of output voltage and the corresponding input voltages for the circuit to operate in the linear region (i.e., Class-A operation) for (a)  $R_L = \infty$  and (b)  $R_L = 500\Omega$ .
  - What is the smallest value of  $R_L$  possible if a 2 V peak sine wave is produced at the output?
  - What is the corresponding power conversion efficiency?
- Consider the class-AB output stage in Figure 1b. Assume that all transistors are matched, with parameters  $V_+ = -V_- = 12V$  and  $\beta = 40$ ,  $V_{BE}(npn) = V_{BE}(pnp) = 0.7V$ ,  $R_1 = R_2 = 250\Omega$ ,  $R_3 = R_4 = 0\Omega$ ,  $R_L = 8\Omega$ . Hint: You can practically assume that  $i_{E3} = i_O$ .
  - For  $v_I = 0V$ , determine  $i_{E1}$ ,  $i_{E2}$ ,  $i_{B1}$ , and  $i_{B2}$ .
  - For  $v_I = 5V$ , determine  $i_O$ ,  $i_{E1}$ ,  $i_{E2}$ ,  $i_{B1}$ ,  $i_{B2}$ , and  $i_I$ .
  - Using the results of part (b), determine the current gain of the output stage.
- Consider the class-AB MOSFET output stage, shown in Figure 2a. The circuit parameters are  $I_{Bias} = 0.2mA$ ,  $R_L = 1k\Omega$ . The transistor parameters are  $V_{TH,n} = 0.8V$ ,  $k'_n = 100\mu A/V^2$ ,  $V_{TH,p} = -0.8V$ ,  $k'_p = 40\mu A/V^2$ . For the quiescent condition, assume  $V_{GS,3} = V_{SG,4}$  and  $V_{GS,1} = V_{GS,2}$ . Assume  $\lambda = 0$  for all transistors.
  - If  $V_i = -1.5V$ ,  $V_O = 0V$ , and  $i_{D1} = i_{D2} = 0.5mA$ , determine the  $W/L$  ratio of each transistor.
  - Assuming a voltage drop across  $I_{Bias}$  of 0.2 V and  $V_i = -1.5V$ , find the maximum and minimum limits of  $V_O$ .
- Using SPICE, plot the input/output characteristic of the circuit shown in Figure 2b for  $-2V < V_{in} < +2V$ . Also, plot the output waveform for an input sinusoid having a peak amplitude of 2 V. How do these results change if the load resistance is raised to  $16\Omega$ ? Use 2N2222 npn and 2N2907 pnp transistors in LTSpice.

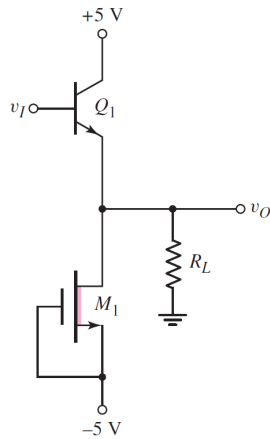


Fig 1a. The figure of Question 1

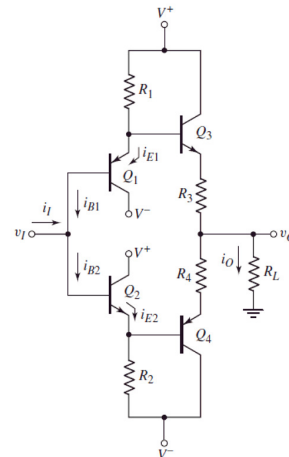


Fig 1b. The figure of Question 2

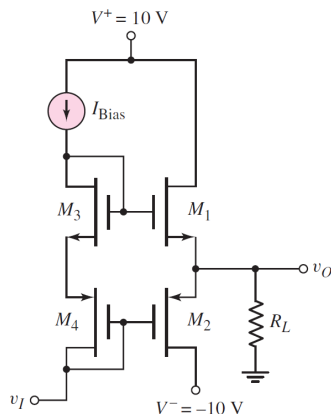


Fig 2a. The figure of Question 3

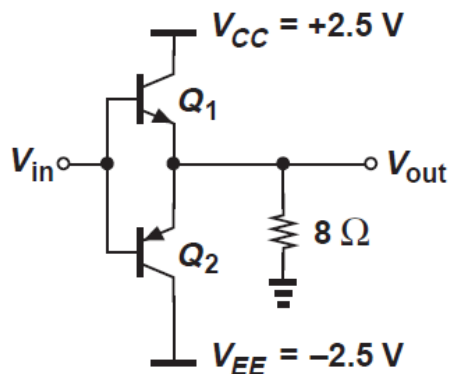


Fig 2b. The figure of Question 4